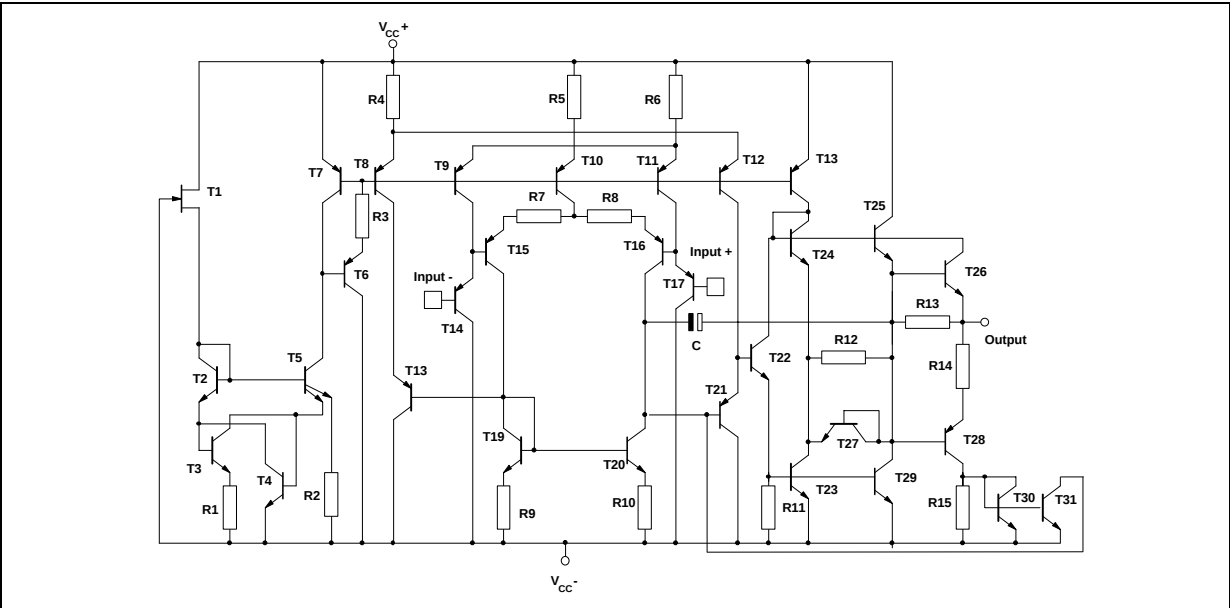


SCHEMATIC DIAGRAM (for 1/4 MC33174)



MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	± 22	V
V_{id}	Differential Input Voltage	see note 1)	V
V_i	Input Voltage	see note 1	V
	Output Short Circuit Duration	Indefinite	s
T_{oper}	Operating Free-Air Temperature range MC33174 MC35174	-40 to 105 -55 to 125	$^{\circ}\text{C}$
T_j	Junction Temperature	150	$^{\circ}\text{C}$
T_{stg}	Storage Temperature	-65 to 150	$^{\circ}\text{C}$

1. Either or both input voltages must not exceed the magnitude of V_{cc} .

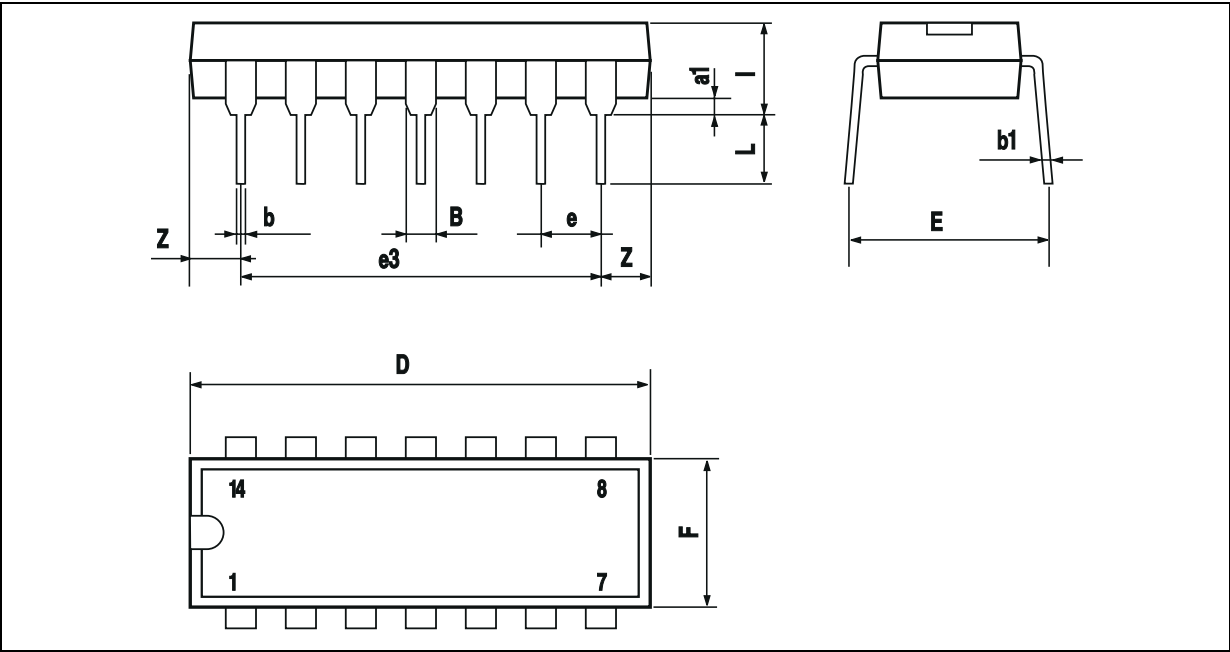
OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	± 2 to ± 22	V

ELECTRICAL CHARACTERISTICS
 $V_{CC}^{+} = +15V$, $V_{CC}^{-} = -15V$, R_L connected to Ground, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input Offset Voltage $V_{CC}^{+} = +15V$, $V_{CC}^{-} = -15V$, $V_{ic} = 0V$ $V_{CC}^{+} = 5V$, $V_{CC}^{-} = 0V$, $V_{ic} = 0V$, $V_o = 1.4V$ $V_{CC}^{+} = +15V$, $V_{CC}^{-} = -15V$, $V_{ic} = 0V$, $T_{min.} \leq T_{amb} \leq T_{max.}$		1 1	4.5 5 6.5	mV
DV_{io}	Input Offset Voltage Drift		10		$\mu V/^{\circ}C$
I_{io}	Input Offset Current ($V_{ic} = 0V$) $T_{min.} \leq T_{amb} \leq T_{max.}$		5	20 40	nA
I_{ib}	Input Bias Current ($V_{ic} = 0V$) $T_{min.} \leq T_{amb} \leq T_{max.}$		20	100 200	nA
A_{vd}	Large Signal Voltage Gain ($R_L = 10k\Omega$, $V_o = \pm 10V$) $T_{min.} \leq T_{amb} \leq T_{max.}$	50 25	100		V/mV
V_{OH}	High Level Output Voltage $V_{CC}^{+} = 5V$, $V_{CC}^{-} = 0V$, $R_L = 10k\Omega$ $V_{CC}^{+} = +15V$, $V_{CC}^{-} = -15V$, $R_L = 10k\Omega$ $V_{CC}^{+} = +15V$, $V_{CC}^{-} = -15V$, $R_L = 10k\Omega$, $T_{min.} \leq T_{amb} \leq T_{max.}$	3.5 13.6 13.3	4.2 14.2		V
V_{OL}	Low Level Output Voltage $V_{CC}^{+} = 5V$, $V_{CC}^{-} = 0V$, $R_L = 10k\Omega$ $V_{CC}^{+} = +15V$, $V_{CC}^{-} = -15V$, $R_L = 10k\Omega$ $V_{CC}^{+} = +15V$, $V_{CC}^{-} = -15V$, $R_L = 10k\Omega$, $T_{min.} \leq T_{amb} \leq T_{max.}$		0.1 -14	0.15 -13.6 -13.3	V
I_{sc}	Output Short Circuit Current ($V_{id} = \pm 1V$, $V_o = 0V$) Source Sink	3 15	6 27		mA
V_{icm}	Input Common Mode Voltage Range $T_{min.} \leq T_{amb} \leq T_{max.}$	V_{CC}^{-} to $(V_{CC}^{+} - 1.8)$ V_{CC}^{-} to $(V_{CC}^{+} - 2.2)$			V
CMR	Common-mode Rejection Ratio ($V_{ic} = V_{icm \text{ min.}}$)	80	100		dB
SVR	Supply Voltage Rejection Ratio ($V_{CC} = \pm 5$ to $\pm 15V$)	80	100		dB
I_{CC}	Supply Current $V_{CC}^{+} = 5V$, $V_{CC}^{-} = 0V$, no load $V_{CC}^{+} = +15V$, $V_{CC}^{-} = -15V$, no load $V_{CC}^{+} = +15V$, $V_{CC}^{-} = -15V$, no load, $T_{min.} \leq T_{amb} \leq T_{max.}$		200 220	250 250 300	μA
SR	Slew Rate ($V_i = \pm 10V$, $R_L = 10k\Omega$, $C_L = 100pF$)	1.6	2		V/ μs
GBP	Gain Bandwidth Product $R_L = 10k\Omega$, $C_L = 100pF$, $f = 100kHz$	1.4	2.1		MHz
ϕ_m	Phase Margin ($R_L = 10k\Omega$, $C_L = 100pF$)		45		Degrees
e_n	Equivalent Input Noise Voltage ($f = 1kHz$)		29		$\frac{nV}{\sqrt{Hz}}$
THD	Total Harmonic Distortion		0.05		%
V_{O1}/V_{O2}	Channel Separation		120		dB

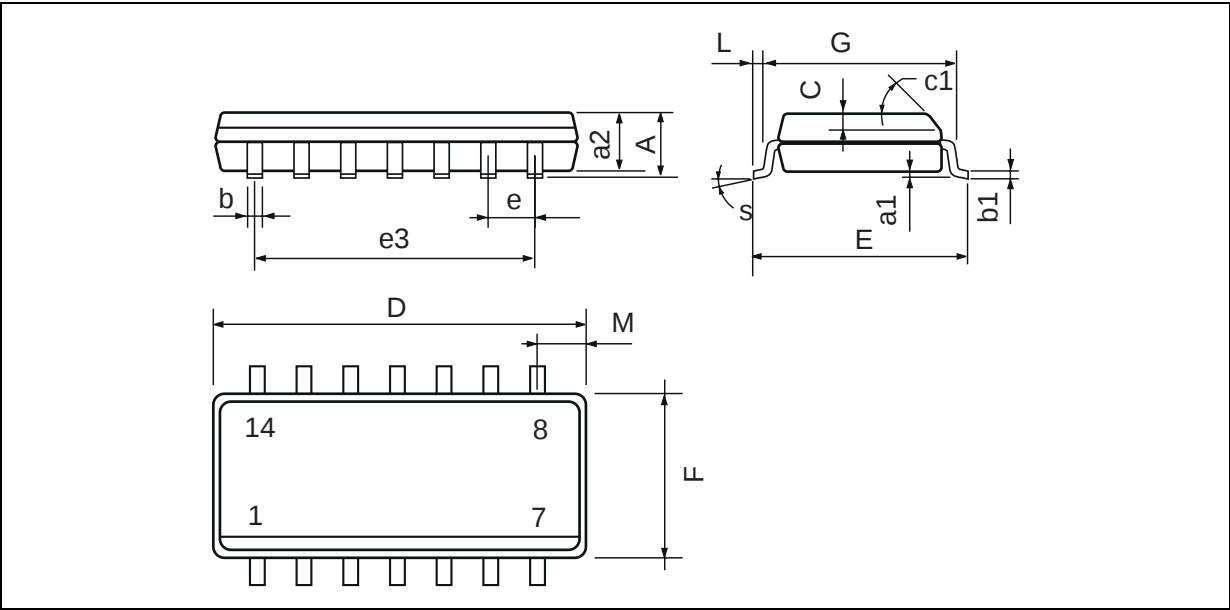
PACKAGE MECHANICAL DATA
14 PINS - PLASTIC DIP



Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
i			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100



PACKAGE MECHANICAL DATA
14 PINS - PLASTIC MICROPACKAGE (SO)



Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.2	0.004		0.008
a2			1.6			0.063
b	0.35		0.46	0.014		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.020	
c1	45° (typ.)					
D (1)	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F (1)	3.8		4.0	0.150		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.020		0.050
M			0.68			0.027
S	8° (max.)					

Note : (1) D and F do not include mold flash or protrusions - Mold flash or protrusions shall not exceed 0.15mm (.066 inc) ONLY FOR DATA BOOK.

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